Diode Semiconductor Device - Page 1 of 1



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01	osure Material:
Glas	
	all Length:
	) inches
	ninal Length:
	een 1.000 inches and 1.500 inches
	all Diameter:
	) inches
	nting Method:
Term	
	ures Provided:
	netically sealed case
	cality Code Justification:
Feat	
	iconductor Material:
Silico	
	age Rating In Volts Per Characteristic:
	regulator voltage
Curr	ent Rating Per Characteristic:
20.00	) milliamperes repetitive peak forward current
Pow	er Rating Per Characteristic:
400.0	) milliwatts total power dissipation
Maxi	mum Operating Tempurature Per Measurement Point:
175.0	) degrees celsius ambient air
Spec	sial Features:
Item	must comply with rqmt of desc production standard no. L00819
Term	ninal Type And Quantity:
2 uni	nsulated wire lead
Shel	f Life:
N/a	
Unit	Of Measure:
Dem	ilitarization:
No	
Fiig:	
	ao